

SILICON TRANSISTOR ARRAY

μ PA1428A

NPN SILICON POWER TRANSISTOR ARRAY HIGH SPEED SWITCHING USE (DARLINGTON TRANSISTOR) INDUSTRIAL USE

DESCRIPTION

The μ PA1428A is NPN silicon epitaxial Darlington Power Transistor Array that built in Surge Absorber 4 circuits designed for driving solenoid, relay, lamp and so on.

FEATURES

- · Surge Absorber built in.
- · Easy mount by 0.1 inch of terminal interval.
- High hee for Darlington Transistor.

ORDERING INFORMATION

Part Number	Package	Quality Grade
μ PA1428A H	10 Pin SIP	Standard

Please refer to "Quality grade on NEC Semiconductor Device" (Document number IEI-1209) published by NEC Corporation to know the specification of quality grade on the devices and its recommended applications.

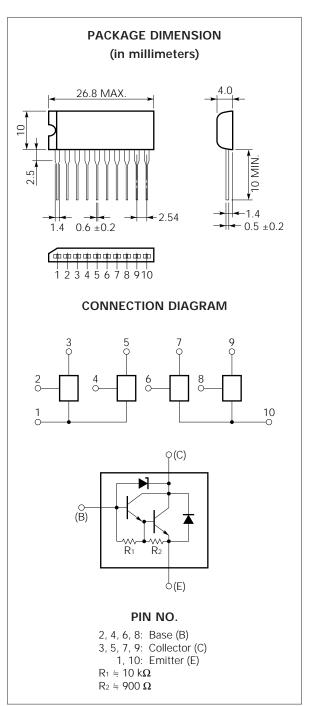
ABSOLUTE MAXIMUM RATINGS (Ta = 25 °C)

Collector to Base Voltage	Vсво	60 ±10	V
Collector to Emitter Voltage	V_{CEO}	60 ±10	V
Emitter to Base Voltage	V_{EBO}	8	V
Surge Sustaining Energy	Eceo(sus)	30	mJ/unit
Collector Current (DC)	Ic(DC)	±2	A/unit
Collector Current (pulse)	Ic(pulse)*	±3	A/unit
Base Current (DC)	IB(DC)	0.2	A/unit
Total Power Dissipation	P _{T1} **	3.5	W
Total Power Dissipation	P _{T2} ***	28	W
Junction Temperature	Tj	150	.C
Storage Temperature	Tstg -5	55 to +15	0 °C

* PW \leq 350 μ s, Duty Cycle \leq 2 %

** 4 Circuits, Ta = 25 °C

*** 4 Cuircuits, Tc = 25 °C



The information in this document is subject to change without notice.

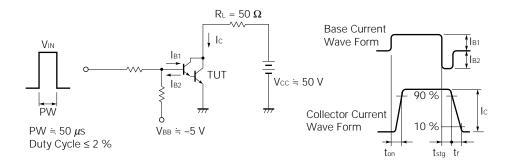


ELECTRICAL CHARACTERISTICS (Ta = 25 °C)

CHARACTERISTIC	SYMBOL	MIN.	TYP.	MAX.	UNIT	TEST CONDITIONS
		TVIII V.				
Collector Leakage Current	Ісво			1	μΑ	Vcb = 40 V, IE = 0
Emitter Leakage Current	Ієво			5	mA	V _{EB} = 5 V, I _C = 0
Collector to Emitter	VcEO(sus)	50	60	70	V	Ic = 1 A, L = 1 mH
Sustaining Voltage						
DC Current Gain	h _{FE1} *	2000		20000	_	Vce = 2 V, Ic = 1 A
DC Current Gain	h _{FE2} *	500			_	Vce = 2 V, Ic = 2 A
Collector Saturation Voltage	VcE(sat) *		1.0	1.5	V	Ic = 1 A, I _B = 1 mA
Base Saturation Voltage	V _{BE(sat)} *		1.7	2	V	Ic = 1 A, I _B = 1 mA
Turn On Time	ton		0.4		μs	Ic = 1 A
Storage Time	tstg		1.5		μs	$I_{B1} = -I_{B2} = 2 \text{ mA}$ $V_{CC} = 50 \text{ V}, R_L = 50 \Omega$ See test circuit
Fall Time	tf		0.4		μs	

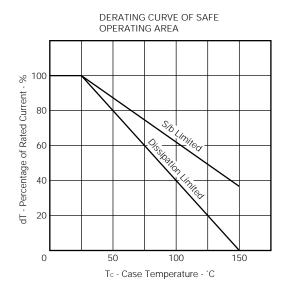
^{*} PW \leq 350 μ s, Duty Cycle \leq 2 %/pulsed

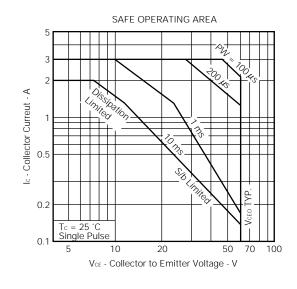
SWITCHING TIME TEST CIRCUIT

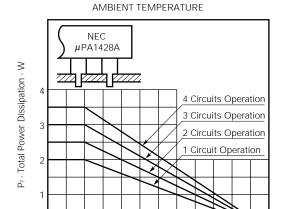




TYPICAL CHARACTERISTICS (Ta = 25 °C)

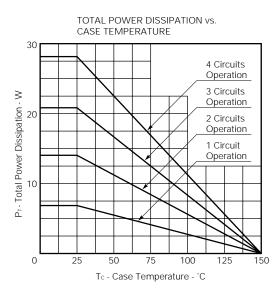


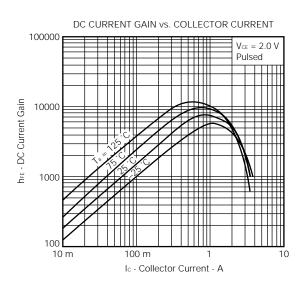


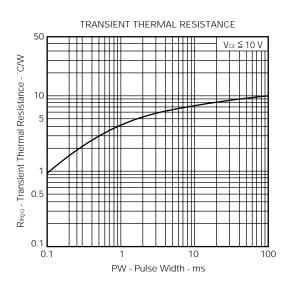


 T_a - Ambient Temperature - ${}^{\circ}C$

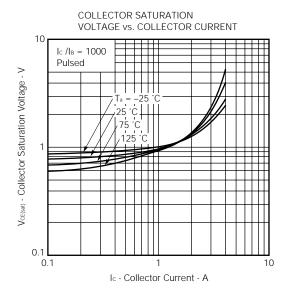
TOTAL POWER DISSIPATION vs.

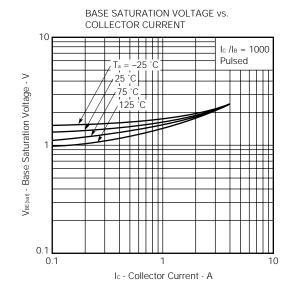


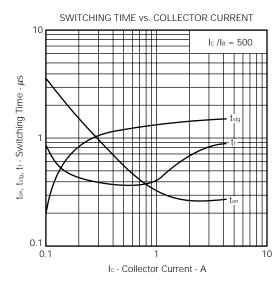


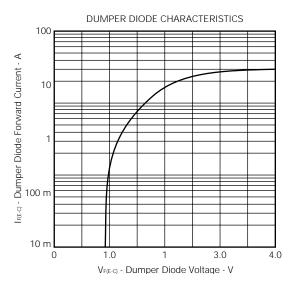














REFERENCE

Document Name	Document No.
NEC semiconductor device reliability/quality control system.	TEI-1202
Quality grade on NEC semiconductor devices.	IEI-1209
Semiconductor device mounting technology manual.	IEI-1207
Semiconductor device package manual.	IEI-1213
Guide to quality assurance for semiconductor devices.	MEI-1202
Semiconductor selection guide.	MF-1134

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